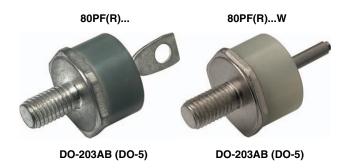
VS-80PF(R)...(W) High Voltage Series

Vishay Semiconductors

Standard Recovery Diodes, Generation 2 DO-5 (Stud Version), 80 A



www.vishay.com

 PRODUCT SUMMARY

 IF(AV)
 80 A

 Package
 DO-203AB (DO-5)

 Circuit configuration
 Single diode

FEATURES

- High surge current capability
- · Designed for a wide range of applications
- Stud cathode and stud anode version
- Wire version available
- Low thermal resistance
- Designed and qualified for multiple level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Battery charges
- Converters
- Power supplies
- Machine tool controls
- Welding

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
		80	A		
I _{F(AV)}	T _C	123	°C		
I _{F(RMS)}		126	A		
I _{FSM}	50 Hz	1200	٨		
	60 Hz	1250	A		
l ² t	50 Hz	7100	A ² s		
	60 Hz	6450	A-5		
V _{RRM}	Range	1400 to 1600	V		
TJ		-55 to 150	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 150 °C mA		
VS-80PF(R)(W)	140	1400	1650	4.5		
V3-00FF(N)(VV)	160	1600	1900	4.5		

Revision: 25-Mar-14

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

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FORWARD CONDUCTION						
PARAMETER	SYMBOL	. TEST CONDITIONS			VALUES	UNITS
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave			80	A
•	. ,				123	°C
Maximum RMS forward current	I _{F(RMS)}				126	A
		t = 10 ms	No voltage		1200	A
Maximum peak, one-cycle forward,	1	t = 8.3 ms	reapplied	Sinusoidal half wave, initial T _J = 150 °C	1250	
non-repetitive surge current	IFSM	t = 10 ms	100 % V _{RRM} reapplied		1000	
		t = 8.3 ms			1050	
	l ² t	t = 10 ms	No voltage reapplied		7100	A ² s
Maximum 12t for fusing		t = 8.3 ms			6450	
Maximum I ² t for fusing		t = 10 ms	100 % V _{RRM} reapplied		5000	
		t = 8.3 ms			4550	
Maximum I²√t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied			71 000	A²√s
Low level value of threshold voltage	V _{F(TO)}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum			0.73	V
Low level value of forward slope resistance	r _f	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum			3.0	mΩ
Maximum forward voltage drop	V _{FM}	I_{pk} = 220 A, T_J = 25 °C, t_p = 400 µs rectangular wave			1.46	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating and storage temperature range	T _J , T _{Stg}		-55 to 180	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.30		
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25	K/W	
Allowable mounting torque		Not lubricated threads, tighting on nut ⁽¹⁾	3.4 (30)		
		Lubricated threads, tighting on nut (1)	2.3 (20)	N⋅m	
		Not lubricated threads, tighting on Hexagon ⁽²⁾	4.2 (37)	(lbf · in)	
		Lubricated threads, tighting on Hexagon ⁽²⁾	3.2 (28)		
Approvimeto weight			15.8	g	
Approximate weight			0.56	OZ.	
Case style See dimensions - link at the end of datasheet DO-203		DO-203A	B (DO-5)		

Notes

⁽¹⁾ Recommended for pass-through holes

⁽²⁾ Torque must be applicable only to Hexagon and not to plastic structure, recommended for holed heatsink

CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.14	0.10				
120°	0.16	0.17				
90°	0.21	0.22	T _J = T _J maximum	K/W		
60°	0.30	0.31				
30°	0.50	0.50				

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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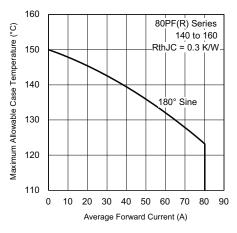


Fig. 1 - Current Ratings Characteristics

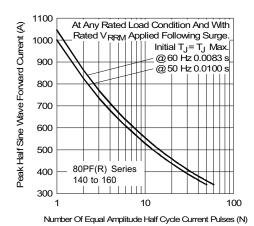


Fig. 2 - Current Ratings Characteristics

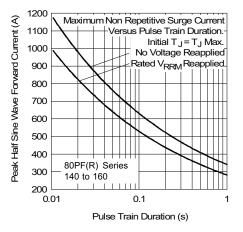


Fig. 3 - Forward Power Loss Characteristics

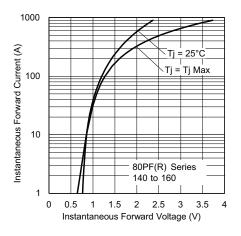


Fig. 4 - Forward Power Loss Characteristics

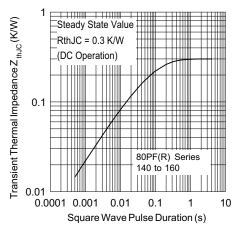


Fig. 5 - Maximum Non-Repetitive Surge Current





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ORDERING INFORMATION TABLE

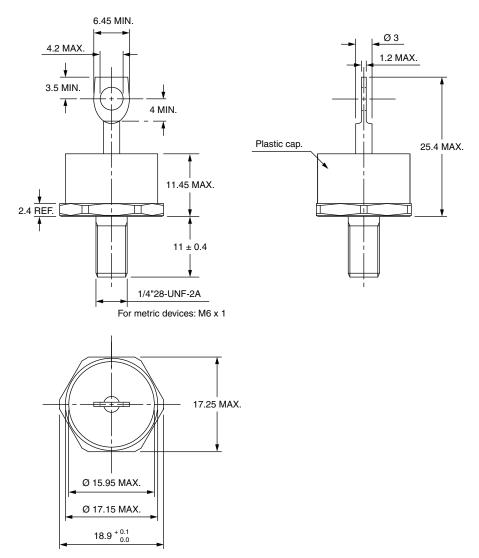
Device code	VS-	80	PF	R	160	w
	1	2	3	4	5	6
	1	- Vish	nay Sem	iconduc	tors pro	duct
	2	- 80 =	= Standa	ard devi	ce	
	3	- PF =	= Plastic	packag	je	
	4	- • No	one = Si	tud norn	nal pola	rity (catl
	_	• R	= Stud	reverse	polarity	(anode
	5	- Volt	age cod	e x 10 =	V _{RRM} (see Vol
	6			tandard		
				nsions f		(R)
		• VV	= vvire	termina	I	

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95345			



DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W), and 95PF(R)...(W) Series

DIMENSIONS FOR 80PF(R), 50PF(R) AND 95PF(R) SERIES in millimeters

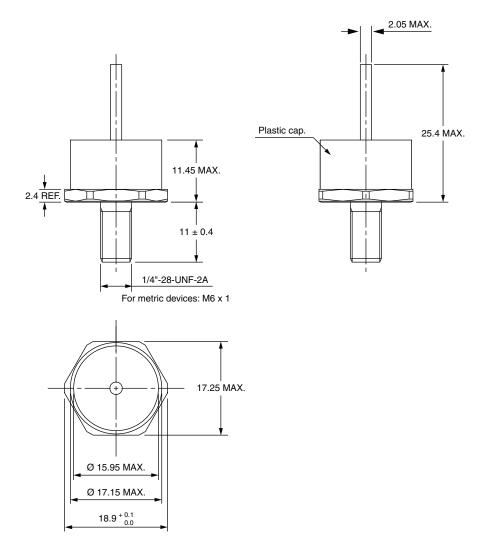


Note

• For metric device please contact factory



DIMENSIONS FOR 80PF(R)...(W), 50PF(R)...(W) AND 95PF(R)...(W) SERIES in millimeters

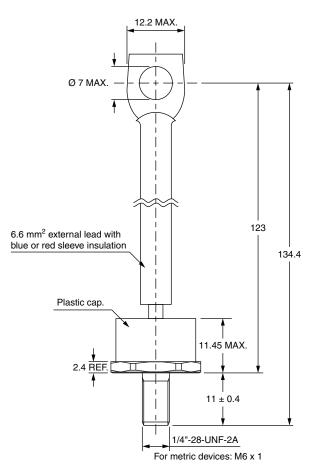


Note

• For metric device please contact factory



DIMENSIONS FOR 52PF(R), 82PF(R) AND 97PF(R) SERIES in millimeters



Note

· For metric device please contact factory



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